# lonoluminescence on α-quartz: Mechanisms and modeling

## Introduction

Ionoluminescence of  $\alpha$ -quartz exhibits two dominant emission bands peaking at 1.9 eV (NBOHCs) and 2.7 eV (STEs). The evolution of the red emission yield does not show a correlation with the concentrations of neither the NBOHC nor with that of other color centers. The blue emission yield closely follows the amorphization kinetics independently measured by RBS/C spectrometry. A simple theoretical model has been proposed; it assumes that the formation and recombination of STEs are the primary event and both, the light emissions and the lattice structural damage are a consequence this phenomenon. The model leads to several simple mathematical equations that can be used to simulate the IL yields and provide a reasonable fit to experimental kinetic data.



Figure 1. IL spectra for Br at 25 MeV. (a) Low fluence (2.5x10<sup>11</sup> cm<sup>-2</sup>) and (b) high fluence (6.5x10<sup>13</sup> cm<sup>-2</sup>).

### References

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•Our data support the assignment of the 1.9 and 2.7 eV emission bands to recombination of NBOHC and STE, respectively. •We found an excellent correlation between the change of slope ( $Y_B$ ) and the damaged fraction (RBS/C). •At a qualitative level the agreement with the experiments is quite satisfactory. •Even at the quantitative level the obtained fits appear very promising, although one is pending of further improvements and refinements of the model.

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